International Rectifier

IR15XB..

15.0 Amps Single Phase Full Wave

Bridge Rectifier

Features

- Diode chips are glass passivated
- Suitable for Universal hole mounting
- Easy to assemble & install on P.C.B.
- High Surge Current Capability
- High Isolation between terminals and molded case (2500 V_{RMS})
- High Thermal Conductivity
- Lead free terminals solderable as per MIL-STD-750, Method 2026
- High Temperature soldering guaranteed at 260°C/ 8-10secs
- UL approval E215862 in progess

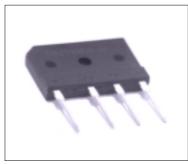
$I_{O(AV)} = 15A$ $V_{RRM} = 200/800V$

Description

These IRXB Series of Single Phase Bridges consist of four glass passivated silicon junction connected as a Full Wave Bridge. These four junctions are encapsulated by plastic molding technique. These Bridges are mainly used in Switch Mode power supply, Induction cooker, Airconditioner, Washing Machine and Microwave oven.

Major Ratings and Characteristics

Parameters		IR15XB	Units
Io		15	А
	@T _C	107	°C
I _{FSM}	@50Hz	240	Α
	@60Hz	250	Α
I ² t	@50Hz	288	A ² s
	@60Hz	260	A ² s
V_{RRM}	range	200 to 800	V
T _J		- 55 to 150	°C



IR15XB..

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V _{RRM} , max repetitive peak rev. voltage T _J = T _J max.	V _{RMS} , max RMS voltage T _J =T _J max.	I_{RRM} max. @ rated V_{RRM} $T_{J} = 25^{\circ}C$	I _{RRM} max. @ rated V _{RRM} T _J = 150°C
IR15XB	02	200	140	μA 5	μA 250
	04	400	280	5	250
	06	600	420	5	250
	08	800	560	5	250

Forward Conduction

	Parameters	IR15XB	Unit	Conditions	
Io	Maximum DC output current	15	Α	T _C =100°C, Resistive & inductive load	
I _{ESM}	Maximum peak, one-cycle	240		t = 10ms	
	non-repetitive surge current,				
	following any rated load condition	250		t = 8.3ms	T _J =150°C
	and with rated V _{RRM} reapplied				
I ² t	Maximum I ² t for fusing,	288	A ² s	t = 10ms	
	initial T _J =T _J max	260		t = 8.3ms	
V _{FM}	Maximum peak forward voltage	1.05	V	T _J =25°C, I _{FM} =7.	5A
	per diode				
I _{RM}	Typical peak reverse leakage	5.0	μA	T _J = 25°C, 100%	V _{RRM}
	current per diode	400		T _J =150°C, 100%	V _{RRM}
V_{RRM}	Maximum repetitive peak	200 to 800	V		
	reverse voltage range				

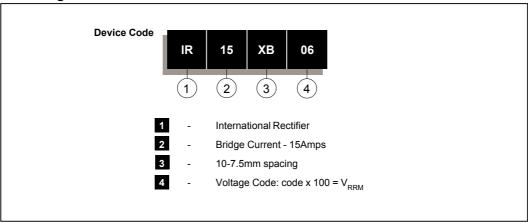
Thermal and Mechanical Specifications

	Parameters	IR15XB	Unit	Conditions
T _J	Operating and storage temperature range	-55 to 150	°C	
R _{thJC}	Max.thermalresistance junction to case	1.5	°C/W	At DC rated current (1)
R _{thJA}	Thermal resistance, junction to ambient	22	°C/W	At DC rated current (2)
W	Approximateweight	7.4(0.26)	g(oz)	
Т	Mounting Torque	1.0	Nm	Bridge to Heatsink
		9.0	Lb.in	

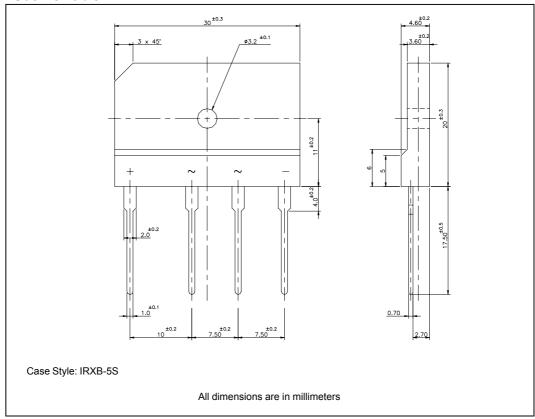
Note (1): Bridge mounted on Aluminun heat sink, use silicon thermal compound for heat transfer and bolt down using 3mm screw

(2): Bridges mounted in free air without heatsink.

Ordering Information Table



Outline Table



Preliminary Data Sheet 12788 10/01

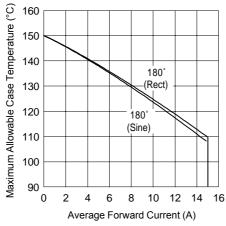


Fig. 1 - Current Ratings Characteristics

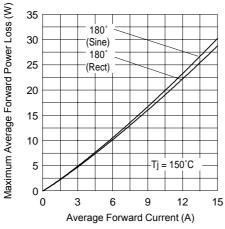


Fig. 3 - Total Power Loss Characteristics

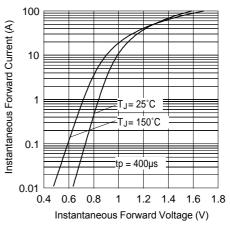
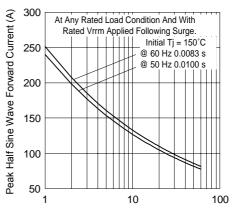


Fig. 2 - Forward Voltage Drop Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 4 - Maximum Non-Repetitive Surge Current

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial and Consumer Level.

Qualification Standards can be found on IR's Web site.



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